Ultrathin SnO$_2$ Nanosheets: Oriented Attachment Mechanism, Nonstoichiometric Defects, and Enhanced Lithium-Ion Battery Performances

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ABSTRACT: We successfully synthesized large-scale and highly pure ultrathin SnO$_2$ nanosheets (NSs), with a minimum thickness in the regime of ca. 2.1 nm as determined by HRTEM and in good agreement with XRD refinements and AFM height profiles. Through TEM and HRTEM observations on time-dependent samples, we found that the as-prepared SnO$_2$ NSs were assembled by “oriented attachment” of preformed SnO$_2$ nanoparticles (NPs). Systematic trials showed that well-defined ultrathin SnO$_2$ NSs could only be obtained under appropriate reaction time, solvent, additive, precursor concentration, and cooling rate. A certain degree of nonstoichiometry appears inevitable in the well-defined SnO$_2$ NSs sample. However, deviations from the optimal synthetic parameters give rise to severe nonstoichiometry in the products, resulting in the formation of Sn$_3$O$_4$ or SnO. This finding may open new accesses to the fundamental investigations of tin oxides as well as their intertransition processes. Finally, we investigated the lithium-ion storage of the SnO$_2$ NSs as compared to SnO$_2$ hollow spheres and NPs. The results showed superior performance of SnO$_2$ NSs sample over its two counterparts. This greatly enhanced Li-ion storage capability of SnO$_2$ NSs is probably resulting from the ultrathin thicknesses and the unique porous structures: the nanometer-sized networks provide negligible diffusion times of ions thus faster phase transitions, while the “breathable” interior porous structure can effectively buffer the drastic volume changes during lithiation and delithiation reactions.

INTRODUCTION

Nowadays, the fast development and demand in industry intensively focus on various applications of nanomaterials. The main interest lies in more rational design and precise control over specialized morphologies of nanomaterials with tailored properties. Among various nanostructures, dimensionality is one of the most defining parameters which significantly control the ways in which materials behave. Until now, 0-D (quantum dots), 1-D (nanowires, nanotubes, nanorods), and 3-D crystals are abundantly documented, while 2-D structures are far less reported. Even since the finding of graphene, the combination of unique molecular geometry with exciting properties triggered intensive efforts in synthesizing other 2-D ultrathin nanosheet materials. Furthermore, 3-D hierarchical structures produced by self-assembly and higher order organization of nanosheet building blocks attract extensive attention due to their collective optical, electrical, and magnetic properties since the complicated spatial arrangement can provide both extraordinarily high activated surface area and robustness. However, it is still highly desirable to develop facile and reliable synthesis routes, which do not require catalysts, expensive or toxic templates, and tedious procedures for rational design of those hierarchical structures.

Solution-based procedures (known as “bottom-up” approach) for the syntheses of nanomaterials are very promising to precisely control their sizes and morphologies. However, the crystallization from a solution is still not fully understood. Classical crystal growth mode has been used to interpret crystallization processes since about 100 years ago. It is represented by atom additions to preformed nuclei and dissolution of unstable phases with concomitantly reprecipitation of stable phases. Alternatively, a particle-based aggregation mode named “oriented attachment” mechanism was recently proposed by Penn and Banfield, in which secondary crystal intermediates are abundantly documented, while 2-D structures are far less reported. Even since the finding of graphene, the combination of unique molecular geometry with exciting properties triggered intensive efforts in synthesizing other 2-D ultrathin nanosheet materials. Furthermore, 3-D hierarchical structures produced by self-assembly and higher order organization of nanosheet building blocks attract extensive attention due to their collective optical, electrical, and magnetic properties since the complicated spatial arrangement can provide both extraordinarily high activated surface area and robustness. However, it is still highly desirable to develop facile and reliable synthesis routes, which do not require catalysts, expensive or toxic templates, and tedious procedures for rational design of those hierarchical structures.

Supporting Information

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SnO2, due to its intrinsic nonstoichiometry from oxygen vacancies, is regarded as n-type semiconductor with wide band gap energy of 3.6 eV. So far, different structures33−38 have been investigated as well as their potential applications in gas sensors,33−37 spintronics,38,39 photocatalysis,40 and supercapacitors,41−43 etc. Specifically, it attracts worldwide attention as the next generation lithium-ion battery anode materials.30,44−48 Recently, our group successfully synthesized a new SnO2 NSs structure by a template-free and surfactant-free one-pot hydrothermal method. The as-obtained SnO2 nanostructures feature sheet-based hierarchical configurations with a BET surface area as high as 180 m2/g. Furthermore, they were found to possess room-temperature ferromagnetism as well as being a potential anode alternative in lithium-ion syntheses.49,50,119

### EXPERIMENTAL SECTION

#### Materials Syntheses

All reagents were purchased from the indicated suppliers and used without any further purification: tin dichloride dihydrate (SnCl2·2H2O, Alfa Aesar, 98%), analytical grade ethanol, NH4H2O (25−28 wt %), and urea (98%) (Sinopharm Chemical Reagent Co. Ltd.). In a typical experiment, SnCl2·2H2O powder was added to a mixture of ethanol (EtOH) and water with r value (EtOH vol % in the solvent of EtOH and water) 0−100%, and the solution turned into a white turbid suspension. Afterward, sufficient mineralizer (i.e., 0.8 M NH4H2O or urea) was added to reach a Sn(II) concentration of 6.8−31.6 mM, and the solution color turned to darken yellow-white. The obtained yellow-white turbid suspension was magnetically stirred for 10 min before transferred to a Teflon-lined stainless steel autoclave and then heated in an electric oven at 120 °C for a reaction time from 4 to 48 h. After natural or fast cooling, the yellow product was harvested by centrifugation and dried at 50 °C overnight. The detailed experimental parameters about the reaction time (t, 0−48 h), solvent (r value, 0−100%), additives (NH4H2O, urea), and precursor concentration (c, 6.8−31.6 mM) for the corresponding structures and morphologies of the products are listed in Table 1. (The cooling rate of the autoclave in this table is default as rapid cooling using an ice−water bath.)

#### Materials Characterizations

The products were characterized by X-ray diﬀractometry PANalytical X pert Pro using Cu Ka radiation (λ = 1.5416 Å). Transmission electron microscopy (TEM) Philips FEI 200CX operated at 160 kV, high-resolution transmission electron microscopy (HRTEM), scanning electron microscopy (SEM), X-ray photoelectron spectroscopy (XPS), atomic force microscopy (AFM), ultra-violet−visible spectrophotometry (UV−vis), etc. was used. It was found that these SnO2 NSs were formed by “oriented attachment” of initial NPs. AFM height profile and HRTEM cross-section images indicated the minimum thickness of about 2.1 nm, leading to optical band gap energy of 4.7 eV. Besides, inherent nonstoichiometry resulting in intermediate tin oxides and SnO was further examined by both HRTEM images and XPS. Finally, we compared the lithium-ion storage of the SnO2 NSs with SnO2 hollow spheres and NPs. The results showed quite enhanced performance of SnO2 NSs sample over its two counterparts.

#### Electrochemical Measurements

The electrochemical measurements were carried out using homemade button cells with lithium metal as the counter and reference electrodes at room temperature (25 °C). The electrode consisted of active material (SnO2), conductivity agent (acetylene black, Alfa Aesar), and polymer binder (poly(vinylidene difluoride),

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**Table 1. Conditions of Representative Experimental Conditions Investigated in This Work**

<table>
<thead>
<tr>
<th>sample</th>
<th>reaction time (h)</th>
<th>precursor (SnCl2·2H2O) concn (mM)</th>
<th>r value (%</th>
<th>additive (0.8 M)</th>
<th>structures and morphologies</th>
</tr>
</thead>
<tbody>
<tr>
<td>SA1</td>
<td>4</td>
<td>15.8</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 + Sn3O4(OH)3, NPs</td>
</tr>
<tr>
<td>SA2</td>
<td>5</td>
<td>15.8</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 + Sn3O4(OH)3, NPs + NSs</td>
</tr>
<tr>
<td>SA3</td>
<td>6</td>
<td>15.8</td>
<td>50</td>
<td>NH4H2O</td>
<td>well-defined ultrathin SnO2 NSs</td>
</tr>
<tr>
<td>SA4</td>
<td>24</td>
<td>15.8</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 NSs + trivial SnO2 NSs</td>
</tr>
<tr>
<td>SA5</td>
<td>48</td>
<td>15.8</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 NSs + trivial SnO2 NSs</td>
</tr>
<tr>
<td>SA6</td>
<td>6</td>
<td>15.8</td>
<td>0</td>
<td>NH4H2O</td>
<td>SnO2 nanolines + NPs</td>
</tr>
<tr>
<td>SA7</td>
<td>6</td>
<td>15.8</td>
<td>25</td>
<td>NH4H2O</td>
<td>SnO2 NSs + trivial NPs</td>
</tr>
<tr>
<td>SA8</td>
<td>6</td>
<td>15.8</td>
<td>75</td>
<td>NH4H2O</td>
<td>SnO2 NPs + trivial NPs</td>
</tr>
<tr>
<td>SA9</td>
<td>6</td>
<td>15.8</td>
<td>100</td>
<td>NH4H2O</td>
<td>SnO2 hollow spheres</td>
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<tr>
<td>SA10</td>
<td>6</td>
<td>15.8</td>
<td>50</td>
<td>none</td>
<td>SnO2 NPs</td>
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<tr>
<td>SA11</td>
<td>6</td>
<td>15.8</td>
<td>50</td>
<td>urea</td>
<td>SnO2 NPs + trivial SnO2 NSs</td>
</tr>
<tr>
<td>SA12</td>
<td>6</td>
<td>6.8</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 NSs without hierarchical structure</td>
</tr>
<tr>
<td>SA13</td>
<td>6</td>
<td>31.6</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 NSs + unreached SnO2(OH)3</td>
</tr>
<tr>
<td>SA14</td>
<td>6</td>
<td>15.8 (SnCl4·5H2O)</td>
<td>50</td>
<td>NH4H2O</td>
<td>SnO2 NPs</td>
</tr>
<tr>
<td>SA15</td>
<td>6</td>
<td>15.8</td>
<td>50</td>
<td>NH4H2O + 50 μL H2O2</td>
<td>SnO2 NPs</td>
</tr>
</tbody>
</table>

*The cooling rate in this table is default as rapid cooling using an ice−water bath. **NPs stands for nanoparticles. **NSs stands for nanosheets.*
PVDF, Aldrich) by a weight ratio of 80:10:10. The active material loading in each electrode (about 15 mm in diameter) was typically 1–2 mg. The electrolyte was 1 M LiPF₆ in a 50:50 mixture of ethylene carbonate and diethyl carbonate. Cell assembly was carried out in an Ar-filled glovebox with the concentrations of water vapor and oxygen below 1 ppm. The working electrode was measured at room temperature in the whole process. The cell was charged and discharged at a constant current of 0.2 C (156 mA/g) and a fixed voltage window between 2 V and 10 mV.

### RESULTS AND DISCUSSION

**Sn₆O₄(OH)₄ Intermediate.** In this experiment, we used Sn(II)Cl₂ as the precursor, which eventually underwent oxidation to form Sn(IV)O₂ under hydrothermal condition. Actually, before oxidized, Sn(II) was found to be in the form of Sn(II)₆O₄(OH)₄, which was explicitly revealed by XRD (see Supporting Information, Figure S1). This XRD result indicated that, at ambient condition, the precursor SnCl₂ mainly transformed into poorly crystallized Sn₆O₄(OH)₄ (Joint Committee on Powder Diffraction Standards (JCPDS) card No. 46-1486, space group: P̅4₁2̅1c, a = 7.9268 Å, c = 9.1025 Å) after sequentially mixing with ethanol, water, and NH₃·H₂O. Actually, even if NH₃·H₂O was not added, SnCl₂ would still react with water to form Sn₆O₄(OH)₄. However, the addition of NH₃·H₂O quite favored this transition judging from the severe darkening of suspension color (from white to dark yellow-white), thus leading to higher yield of Sn₆O₄(OH)₄.

**Characterization of Ultrathin SnO₂ NSs.** Figure 1 displays a low-magnification TEM overview image of the as-prepared SnO₂ NSs (t = 6 h, c = 15.8 mM, r = 50% with 0.8 M NH₃·H₂O at 120 °C with rapid cooling).

![Figure 1. TEM overview of the as-synthesized SnO₂ NSs (sample SA3, t = 6 h, c = 15.8 mM, r = 50% with 0.8 M NH₃·H₂O at 120 °C with rapid cooling).](Image)

The sample features high purity in the form of well-defined NSs. The light regions suggest planar or bended thin sheets lying on the substrate, with edge lengths most likely less than 100 nm in lateral dimensions and thicknesses of about 5 nm. Relatively dark regions indicate that some sheets may either lie aslant, perpendicularly to the substrate or spontaneously convolute due to minimization of surface energy. This sample is also investigated by SEM, which further confirms its high morphological purity (see Supporting Information, Figure S2). To obtain thermal stability, these SnO₂ NSs gradually grow into 3-D self-organized architecture, as demonstrated for ultrathin TiO₂ and zeolite NSs.

Figure 2 shows the indexed XRD patterns of samples obtained from various reaction times (4, 5, and 6 h, named as sample SA1, SA2, and SA3, respectively) while keeping the other conditions identical (c = 15.8 mM, r = 50%, 0.8 M NH₃·H₂O at 120 °C with rapid cooling). Standard peak positions and intensities are accordingly marked for Sn₆O₄(OH)₄ (JCPDS No. 46-1486) and SnO₂ (JCPDS No. 41-1445). In this experiment, we used Sn(II)Cl₂ as the precursor, which eventually underwent oxidation to form Sn(IV)O₂ under hydrothermal condition. Actually, before oxidized, Sn(II) was found to be in the form of Sn(II)₆O₄(OH)₄, which was explicitly revealed by XRD (see Supporting Information, Figure S1). This XRD result indicated that, at ambient condition, the precursor SnCl₂ mainly transformed into poorly crystallized Sn₆O₄(OH)₄ (Joint Committee on Powder Diffraction Standards (JCPDS) card No. 46-1486, space group: P̅4₁2̅1c, a = 7.9268 Å, c = 9.1025 Å) after sequentially mixing with ethanol, water, and NH₃·H₂O. Actually, even if NH₃·H₂O was not added, SnCl₂ would still react with water to form Sn₆O₄(OH)₄. However, the addition of NH₃·H₂O quite favored this transition judging from the severe darkening of suspension color (from white to dark yellow-white), thus leading to higher yield of Sn₆O₄(OH)₄.

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**Figure 2. XRD patterns of the products synthesized by 4 h (SA1), 5 h (SA2), and 6 h (SA3) while keeping other parameters constant (c = 15.8 mM, r = 50%, 0.8 M NH₃·H₂O at 120 °C with rapid cooling). Standard peak positions and intensities are accordingly marked for Sn₆O₄(OH)₄ (JCPDS No. 46-1486) and SnO₂ (JCPDS No. 41-1445).**

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Figure 3a–d shows representative TEM images of both Sn₆O₄(OH)₄ intermediate and three products studied in Figure 2a (samples SA1, SA2, and SA3). From these pictures, one can clearly see an evolution from poorly crystallized intermediate to final nanosheet-based hierarchical architectures. The morpho-
elucidate the growth mechanism of SnO$_2$ NSs, we also order to deeper understand the evolution processes and rutile SnO$_2$ (JCPDS card No. 41-1445), which is in good well indexed as (110), (101), (200), (211), and (301) planes of the SAED pattern of sample SA3 (inset of Figure 3d) can be diffraction (SAED) patterns (lower right insets). In addition, corroborated in their corresponding selected-area electron (Figure 3e performed HRTEM on a random site in each TEM image (210), (112), and (211) planes of Sn$_6$O$_4$(OH)$_4$ crystal (JCPDS card No. 46-1486). Besides these short-range ordered lattices, of (110), (101), and (211) planes. However, these correlation of SnO$_2$ (101) planes were clearly detected in four products, from yellow-white (Sn$_6$O$_4$(OH)$_4$) to yellow (sample SA1) and then dark yellow (sample SA3). Usually, the intrinsic SnO$_2$ nanocrystal is white due to reflection of visible light, which results from its wide band gap of 3.6 eV. In this case, the aforementioned color variation trend may be mainly attributed to “F-centers” brought by a potential increase in oxygen vacancies in the samples, which will be discussed in the following sections.

Oriented Attachment Mechanism of SnO$_2$ NSs. In order to deeper understand the evolution processes and elucidate the growth mechanism of SnO$_2$ NSs, we also performed HRTEM on a random site in each TEM image (Figure 3e−h). In Figure 3e, the lattices can be related to (210), (112), and (211) planes of Sn$_6$O$_4$(OH)$_4$ crystal (JCPDS card No. 46-1486). Besides these short-range ordered lattices, arbitrary aligned atom projections in other sites reveal its partially amorphous character. This finding agrees with its XRD result. After 4 h hydrothermal treatment, the edges of the “clusters” start to render SnO$_2$ rutile structured NPs with lattices of (110), (101), and (211) planes. These particles are randomly oriented, and no sheetlike morphologies are observed. As the reaction time is prolonged to 5 h, similar orientation of SnO$_2$ (101) planes were clearly detected in four areas (denoted by red circles), and the homogeneously shallow contrast across these areas indicates the emergence of 2-dimensional sheets. After 6 h, the lattice fringes in Figure 3h feature highly oriented SnO$_2$ NSs along the [110] direction. Many crystal interfaces and dislocations are observed in the nanosheet. This fact indicates that SnO$_2$ NSs prepared here may be comprised of a number of oriented nanocrystals which fuse into one integrated sheet.

Combining XRD and TEM with HRTEM results, we suggest that the evolution process to SnO$_2$ NSs is through oriented attachment growth fashion. This process is a complex chain reaction, which probably starts by the coalescences of randomly oriented SnO$_2$ NPs obtained from decomposition of Sn$_6$O$_4$(OH)$_4$ and is followed by consecutive rotations in 3-dimensional spaces as well as drastic interfacial relaxations so as to achieve full fusion. A similar phenomenon was already detected by in situ HRTEM observation in the SnO$_2$/TiO$_2$ or PbSe systems.$^{52,63}$

To better verify the above assumptions, the SnO$_2$ NSs samples prepared by 24 h (Figure 4a,c, sample SA4) and 48 h (Figure 4b,d, sample SA5) are also characterized by TEM and HRTEM, respectively. Clearly, the ultrathin NSs in these two samples grow planar than those obtained by 6 h reaction. SAED patterns disclose that the products are mainly rutile SnO$_2$ (JCPDS card No. 41-1445). Figure 4c displays a HRTEM image drawn from Figure 4a; the interplanar distances in the picture are 0.374, 0.334, and 0.282 nm. Two fast Fourier transforms (FFT) of local area are given in the upper corner. Similarly, Figure 4d presents a HRTEM image drawn from Figure 4b. The long-range ordered lattice (with a slight mistilt of $\phi = 2^\circ$) implies that the integrated planar NS is formed after 48 h reaction; namely, full fusion of large numbers of nanocrystals has almost been accomplished. The interplanar distances are measured to be 0.348, 0.335, and 0.282 nm. Surprisingly, these interplanar distances are consistent to a possible Sn$_3$O$_4$ structure proposed by White et al.$^{64}$ (monoclinic, space group: P2$_1$/c, $a = 8.2100\ $Å, $b = 4.9300\ $Å, $c = 5.8500\ $Å, $\beta = 94.7^\circ$) rather than rutile SnO$_2$. In fact, we further employ XRD to ascertain the inherent structure of the products prepared by 48 h. The XRD pattern reveals that most of the products still existed as SnO$_2$ while trivial Sn$_3$O$_4$ were found through asymmetric left shoulder of SnO$_2$ (101) peak.

Figure 3. (a−d) Typical TEM images and corresponding SAED patterns (bottom right corner insets) of Sn$_6$O$_4$(OH)$_4$ 4 h (SA1), 5 h (SA2) and 6 h (SA3) SnO$_2$ samples ($c = 15.8\ $mM, $r = 50\%$, 0.8 M NH$_3$·H$_2$O at 120 °C with rapid cooling). The upper right corner inset in each TEM image discloses the color variation of each sample. (e−h) HRTEM images of the aforementioned four samples drawn from the area denoted by blue squares in (a−d). The dashed blue lines correspond to the obvious crystal interfaces in SnO$_2$ nanostructures. From these pictures, it can be clearly seen that Sn$_6$O$_4$(OH)$_4$ transformed to randomly oriented SnO$_2$ NPs, which further grow into SnO$_2$ NSs through oriented attachment mode.
Inherent Nonstoichiometry in SnO2 NSs. The chemical composition of the as-synthesized SnO2 NSs (sample SA3) was carefully investigated by X-ray photoelectron spectroscopy (XPS) analysis, as shown in Figure 5. From the full spectrum (Figure 5a), only Sn, O, and C elements are observed, and no other impurity peaks exist, which again confirm the purity of SnO2 NSs. The binding energy of C 1s peak at 284.8 eV is used as the reference point for charge correcting. Figure 5b displays the high-resolution O 1s spectrum of this sample. According to the literature, the lower binding energy (centered at 531.1 eV) is attributed to the coordination of oxygen bounded to tin atoms, whereas the higher binding energy component (centered at 532.9 eV) develops due to the loss of oxygen, giving rise to nonstoichiometric defects in SnO2 NSs. The high-resolution Sn 3d spectra are shown in Figure 5c. Both Sn 3d5/2 and Sn 3d3/2 peaks are found to be asymmetric. It has been confirmed by both HRTEM observations and theoretical calculations that the nonstoichiometric oxygen deficiency (SnO2−x) induced by oxygen vacancies (V_o) inevitably results in charge compensation via Sn4+ ions reducing to Sn2+ rather than Sn3+. The chemical shift of ∼0.7 eV between Sn4+ and Sn2+ is accordingly reported from previous studies. On this basis, each Sn 3d peak could be respectively deconvoluted into two peaks (numbered 1, 2, 3, and 4). Peak 1 (centered at 487 eV) and peak 3 (centered at 495.4 eV) correspond to Sn4+ bound to oxygen in SnO2. The spin−orbit splitting of 8.4 eV is consistent with that previously reported. Peak 2 (centered at 486.3 eV) and peak 4 (centered at 494.7 eV) are ascribed to Sn2+ in the matrix. The best fit to Sn 3d5/2 level in Figure 5c presents an area ratio \( \frac{A(Sn^{2+})}{A(Sn^{4+}) + A(Sn^{3+})} = 0.13 \), suggesting that about 13% of Sn ions in SnO2 NSs have been reduced to divalent Sn2+ ions which probably existed as Sn3O4.

In order to elucidate the ultrathin thicknesses of SnO2 NSs, a diluted suspension (sample SA3) was ultrasonicated and drop-cast onto clean silicon wafer and analyzed through atomic force microscopy (AFM). Figure 6 shows the AFM image of this sample and a height profile is taken along a black line. The...
black markers on the right of black line indicate an edge of a single NS, and the thickness is determined to be ~2.1 nm. The red markers on the left of this black line show a height difference of ~5.9 nm; this value is most probably caused by two stacked and/or curled nanosheets. By means of HRTEM image simulation,49 we found that the thicknesses of SnO₂ NSs were about 1.5–3.0 nm on the edge. This expectation is in good agreement with our finding here. To better verify this conclusion, we also carefully investigated some well-defined nanosheets (sample SA3) recorded from 610 to 220 nm. Interestingly, our result is quite different with previous reports.58,76,77 In those works, the absorption partition did not start until ~340 nm; this phenomenon was related with an intrinsically optical transition generating an electron in the conduction band and a hole in the valence band. Whereas in our study, two absorption shoulders (480–320 nm denoted by blue rectangle and 290–250 nm denoted by red rectangle) distinctly exist in the overall spectrum. The high-energy absorption onset of ~290 nm is owing to the electron transition from valence to conduction band, and the visible light absorption from 480 to 320 nm is probably attributed to oxygen vacancies (Vₐ) induced impurity energy states in between the band gap. Moreover, the increasing absorption starting from 480 nm (blue-green light) rendered the SnO₂ sample (SA3) exteriorly yellow, quite in accordance with experimental photograph shown in the inset of Figure 3d. To determine the optical band gap energy for this SnO₂ NSs sample, the following equation is used:

\[(a h \nu) ^n = A (h \nu - E_g) \]  

where \( \alpha \) is the absorption coefficient, \( h \) is Planck’s constant, \( \nu \) is the radiation frequency, \( A \) is the parameter that relates to the effective masses associated with the valence band and conduction band, \( E_g \) is the band gap energy, and the value of \( n \) is 2 for direct band gap semiconductors and \( \frac{1}{2} \) for indirect band gap semiconductors. In this case, \( n \) is 2 for SnO₂ and \( \alpha \) is obtained from UV–vis diffuse reflectance curve using the Kubelka–Munk function:

\[ F(R) = \frac{\alpha}{S} = \frac{(1 - R)^2}{2R} \]  

where \( R \) is the corresponding reflectance intensity at the same energy point (\( h \nu \)) of the above equation and \( S \) is the scattering coefficient. Using these parameters, a curve of \((a h \nu) ^n \) vs photon energy \( h \nu \) is plotted in the inset of Figure 7a, and the optical band gap energy of SnO₂ NSs is estimated to be 4.7 eV from the extrapolated intercept of the linear portion to the plot. This value of band gap is much larger than that for bulk SnO₂ (3.6 eV). For semiconductor nanomaterials, the quantum confinement effect is readily expected to subject to decreasing particle sizes. When the crystal sizes of nanostructures are smaller than its exciton Bohr radius, the effective band gap energy of \( E_{\text{eff}} \) is calculated by eq 3 using the effective mass approximation (EMA):

\[ E_{\text{eff}} = E_g + \frac{\hbar^2 \pi^2}{2 \mu R^2} - \frac{1.8 \mu^2}{4 \varepsilon_0^2 \varepsilon R} + \ldots \]  

where \( E_g \) is the bulk band gap energy, \( h \) is Planck’s constant divided by \( 2 \pi \), \( \mu \) is the effective reduced mass (\( \mu \approx m^* \approx 0.275 m_e \)), \( R \) is the nanocrystal radius, \( \varepsilon_0 \) is the static dielectric constant, and \( \varepsilon = 14 \) for SnO₂.82 In combination with aforementioned XRD, HRTEM, and AFM observations, nearly all the SnO₂ NSs exhibit lateral length from 30 to 80 nm and thicknesses in the regime of ca. 2.1–3.6 nm (i.e., the half-thicknesses are 1.05–1.8 nm, less than the exciton Bohr radius of 2.7 nm83,84). Therefore, the as-synthesized SnO₂ NSs in the
thickness direction are in a rather strong quantum confinement regime, while in the lateral dimensions, the electrons are highly delocalized, leading to negligible confinement effect. By employing \( E_{\text{eff}} \) over the half thickness is drawn (Figure 7b). From this plot, the enlarged band gap energy of 4.7 eV corresponds to the mean half-thickness of \( \sim 1.05 \) nm, namely, \( \sim 2.1 \) nm average thickness for SnO\(_2\) NSs, which in return remarkably well coincides with the minimum thickness observed in AFM and HRTEM cross-section images. In addition, minor Sn\(_3\)O\(_4\) existing in the sample inevitably contributes to the band gap energy. However, it seems that the ultrathin thickness-dependent quantum confinement dominates this band gap widening.

**Synthetic Effect of Specific \( r \) Values.** It is known that structures and morphologies of the as-prepared materials are significantly affected by different reaction conditions. Here we systematically discuss these relationships as follows. Since the \( r \) value (EtOH vol % in the mixture of EtOH−H\(_2\)O) is closely related to the polarity of solvent, we first study this synthetic effect brought by specific \( r \) value of 0% (SA6), 25% (SA7), 75% (SA8), and 100% (SA9) (Figure 8). When \( r = 0\%, \text{i.e. the regime of 300 nm. Regardless of the imperfect spherical appearances, this method offers another facile route to obtain hollow spheres which are always under the spotlight in the field of lithium-ion batteries (LIB)\(^{85–87}\).

**Effect of Additives.** Besides the \( r \) value, the effect of additives is also evaluated. Figure S6a (see Supporting Information) presents a HRTEM capture of the product obtained without adding NH\(_3\)·H\(_2\)O. Interconnected SnO\(_2\) NPs are deduced from hydrothermal treatment of the simple mixture of SnCl\(_2\), EtOH, and H\(_2\)O. The SnO\(_2\) rutile structure is revealed by its interplanar distance of 0.335 nm \( \{110\} \) planes. It is also found that the product yield is much lower than that for the SnO\(_2\) NSs sample. This is probably due to decreased generation of Sn\(_3\)O\(_4\)(OH)\(_4\) without adding NH\(_3\)·H\(_2\)O. Figure S6b (see Supporting Information) shows a typical TEM image of the products obtained by adding 0.8 M urea as additive instead of NH\(_3\)·H\(_2\)O. From this picture, most of the products are NPs, while only a few ill-defined NSs are produced. The SAED pattern confirms SnO\(_2\) NPs with a rutile structure. It is thought that the −OH group of ethanol, −NH\(_2\) group of urea, and NH\(_4\)\(^+\) of aqueous ammonia play important roles as surface-modifying reagent in the reactions.\(^{88–95}\) Because of their different ability to bind to Sn ions or form hydrogen bonds, these functional groups may lead to the variation in surface energy of SnO\(_2\) nanocrystals. Under certain conditions, the spontaneous elimination of high-energy surfaces renders the SnO\(_2\) NPs aggregate in a planar way (as in sample SA3), responsible for the formation of SnO\(_2\) NSs.

**Effect of Precursor Concentrations.** Apart from the aforementioned synthetic parameters, the effect of precursor concentration was then investigated \( (t = 6 \text{ h}, r = 50\%, 0.8 \text{ M NH}_3\cdot\text{H}_2\text{O at 120 °C with rapid cooling}) \) (see Supporting Information, Figure S7). As the precursor concentration was reduced from 15.8 mM (SA3) to 6.8 mM (SA10), most of the SnO\(_2\) existed as crumpled or rippled sheets lying on the substrates. When the concentration increased up to 31.6 mM (SA11), 3-D configuration existed, similar to well-defined SnO\(_2\) NSs sample (SA3). However, it was found that some other amorphous-like spherical clusters also existed. By employing XRD measurements, the product indicated a mixture of both SnO\(_2\) and Sn\(_3\)O\(_4\)(OH)\(_4\) (see Supporting Information, Figure S8). This means that under high precursor concentration no excess oxygen can be supplied to consume all Sn\(_6\)O\(_4\)(OH)\(_4\) intermediate. In this case, the precursor concentration is another strict parameter in controlling the morphology of the final product, and only modest concentration \( \text{i.e., 15.8 mM} \) resulted in pure and well-organized SnO\(_2\) NSs.

**Effect of Cooling Rate.** During our experiments, we found that natural cooling instead of fast cooling of autoclave or prolonged reaction time \( (24 \text{ or 48 h}) \) gave rise to some black byproducts besides SnO\(_2\) NSs (see Supporting Information, Figure S9) which were subsequently confirmed to be SnO by XRD (see Supporting Information, Figure S10). From the XRD results, (002) is distinctly the preferential plane, whereas (101) and (110) peaks are rather weak compared to its standard intensities. In our previous work,\(^{96}\) the surface energies of SnO were calculated by first-principles total energy calculations based on density functional theory (DFT) using the Vienna Ab-initio Simulation Package (VASP) code.\(^{97}\) In the order of increasing energy, the surfaces form a sequence of \{001\} \( < \{110\} < \{112\} < \{111\} < \{101\} \). This calculation result is generally consistent to our XRD information. These precipitates are further examined by SEM and found to be mostly...
single plates or crossed plates. The edge lengths of these plates range from 5 to 20 μm. Figure 9a shows a typical low-magnification view of SnO products deduced from natural cooling to room temperature (SA3 configuration but with natural cooling: \( t = 6 \) h, \( c = 15.8 \) mM, \( r = 50\% \), 0.8 M \( \text{NH}_3\cdot\text{H}_2\text{O} \) at 120 °C). Closer looks at these poorly defined plates are shown in Figure 9b,c. In the untransformed areas (denoted by white pane), nanosheet-based hierarchical structures were clearly seen. It seemed that these NSs gradually dissolved and formed larger SnO crystals. In order to reach the SnO stoichiometry, SnO2 must inevitably be reduced. Interestingly, the \( r \) value is also found to be closely related to the morphologies of SnO. Figure 9d shows a typical low-magnification view of SnO products deduced from natural cooling with SA7 configuration (\( t = 6 \) h, \( c = 15.8 \) mM, \( r = 25\% \), 0.8 M \( \text{NH}_3\cdot\text{H}_2\text{O} \) at 120 °C). It is obvious from this picture that most of the plates are more regular than those shown in Figure 10a, implying a more complete evolution. The upper right insets present three representative morphologies, including both symmetric and asymmetric type crosses. In addition, it should be stressed that SnO phase is more easily formed with the existence of H2O. For instance, natural cooling of sample SA8 (\( r = 100\% \)) rendered exclusively SnO2 (hollow spheres), whereas even rapid cooling of sample SA6 (\( r = 0\% \)) would give a lot of SnO plates (see Supporting Information, Figure S11). After carefully inspecting the interplanar angle, it is found that the “twin model” based on formation mechanism proposed in ref 96 is also available in this case. Two crossed planes shared a common twin plane, i.e., the \{112\} plane, and the angle of 84° indicates that the two twined crystals planes are \{001\} planes. Furthermore, rapid cooling of sample SA4 and SA5 also inevitably left quasi-evolved SnO plates. We believe that the whole phenomenon strongly related with thermodynamic equilibrium in the reaction system.

**Overall Formation Mechanism of SnO2 Nanosheets.** In combination with all the above sections, the product evolution is expressed by reactions i–iv:

\[
6\text{Sn}^{2+} + 12\text{NH}_3\cdot\text{H}_2\text{O} \rightarrow \text{Sn}_6\text{O}_4(\text{OH})_4 + 12\text{NH}_4^+ + 4\text{H}_2\text{O} \quad (i)
\]

\[
\text{Sn}_6\text{O}_4(\text{OH})_4 + 3\text{O}_2 \rightarrow 6\text{SnO}_2 + 3\text{H}_2\text{O} \quad (ii)
\]

\[
3\text{SnO}_2 \rightarrow 2\text{Sn}_3\text{O}_4 + \text{O}_2 \quad (iii)
\]

\[
2\text{Sn}_3\text{O}_4 \rightarrow 6\text{SnO} + \text{O}_2 \quad (iv)
\]

As mentioned before, \( \text{Sn}^{2+} \) ions initially reacts with \( \text{H}_2\text{O} \) to give the hydroxide intermediate \( \text{Sn}_6\text{O}_4(\text{OH})_4 \), which is favored after subsequent adequate addition of \( \text{NH}_3\cdot\text{H}_2\text{O} \) (reaction i). During hydrothermal treatment (high temperature and high pressure),
the solution—air interfaces are enormously expanded during boiling conditions and the exposure to oxygen becomes much higher than at ambient conditions. Thus, the divalent Sn\(^{2+}\) ions easily undergo an oxidation to give tetravalent Sn\(^{4+}\) ions in the form of SnO\(_2\) (reaction ii) until all Sn(II) transformed into Sn(IV) (most likely after 6 h reaction). This process is substantially following an “oriented attachment” mechanism. The preformed crystalline and amorphous SnM(O\(_2\))\(_4\) particles first produce randomly oriented SnO\(_2\) NPs. They further go through consecutive rotations in 3-dimensional space as well as interfacial relaxations so as to achieve full fusion. The solvent and NH\(_3\) as well as interfacial relaxations so as to achieve full fusion. The water/ethanol mixture solvent and NH\(_3\)H\(_2\)O additive play important roles here to control the crystal habits and the NPs surface energies, so that 2-dimensional SnO\(_2\) NSs are produced. By changing \(r\) value or additives, different morphologies of SnO\(_2\), e.g., hollow spheres and NPs, could be achieved.

When the reaction time is due, the temperature decreases, leading to a drastic falloff in the gas—solution interface area and exposure to oxygen. The resulting low partial pressure of oxygen \((P_0)\) no doubt induces reduction processes, giving rise to severe nonstoichiometry of SnO\(_2\). To avoid large-scale intense deviation from SnO\(_2\) stoichiometry, fast cooling using ice—water bath is an effective way. However, it is worthwhile mentioning that no matter how fast the system (e.g., sample SA3) cools down; trivial Sn\(_3\)O\(_4\) inevitably exist in the final products apart from SnO\(_2\) NSs (reaction iii). In addition, based on SEM images in Figure 9 and reaction iii, the as-formed SnO\(_2\) plate are deduced by in situ dissolution of randomly oriented Sn\(_3\)O\(_4\) intermediate and recrystallization in a highly aligned way (reaction iv). This procedure also features an oriented attachment growth mode. In attempts to avoid the nonstoichiometry of SnO\(_2\), we have tried some methods, either bringing in tetravalent Sn(IV) of SnCl\(_4\).H\(_2\)O (SA14) as precursor or adding tiny amount of H\(_2\)O\(_2\) (50 \(\mu\)L, 30 wt %) (SA15) on the basis of SA3 configuration. Under alkaline condition, Sn\(^{4+}\) reacts with OH\(^-\) to form small Sn(OH)\(_4\) particles as the nucleus, which is then easily transformed into SnO\(_2\) NPs without any production of SnO\(_2\) NSs. On the other hand, addition of H\(_2\)O\(_2\) provides excess oxygen, resulting in harsher pressure relative to that in sample SA3 and thus also yielding SnO\(_2\) NPs (see Supporting Information, Figure S12). From this viewpoint, it appears that inherent nonstoichiometry of SnO\(_2\) NSs is unavoidable in this system. In view that p-type SnO and n-type Sn\(_2\)O\(_3\) can form p−n junctions to realize enhanced sensor responses,\(^97\) this work may open alternative routes to the fundamental investigations of tin oxides, their intertransistion processes, and the fabrication of novel functional devices.

**Lithium-Ion Battery Performance of SnO\(_2\) Ultrathin NSs.** During the past decade, SnO\(_2\) was one of the most extensively investigated materials in lithium-ion batteries (LIB) owing to its potential applications in next-generation anode materials. Its theoretical capacity was estimated to be 782 mAh/g, which is more than twice that of commercially applied graphite (372 mAh/g). The possible reaction mechanism of SnO\(_2\)/Li cell was proposed as follows:99–101

SnO\(_2\) + 4Li\(^+\) + 4e\(^-\) \(\rightarrow\) Sn + 2Li\(_2\)O (v)
Sn + xLi\(^+\) + xe\(^-\) \(\rightarrow\) Li\(_x\)Sn (0 \(\leq\) x \(\leq\) 4.4) (vi)

The former reaction is thought to be irreversible with the formation of electrochemically inactive Li\(_2\)O together with partial formation of a solid electrolyte interface (SEI). This irreversible process is responsible for the severe capacity fading in the first few cycles. In contrast, the second reaction is reversible, with repeated alloying and dealloying between Sn and Li ions. However, the application of SnO\(_2\)-based anode materials was somehow impeded by poor capacity retention over long-term cycles. The fast capacity deterioration is mainly ascribed to large stress-induced breakdown of conduction pathways. To relieve this problem, it is suggested that SnO\(_2\) should be in a nanomter-sized frame to shorten the diffusion pathways of Li\(_n\).\(^{102,103}\) be highly conducting to promote lithium insertion/extraction,\(^{104}\) and possess interior hollow spaces to accommodate large volume change.\(^{56,65–87,105}\) Figure 10a shows a representative cyclic voltammograms (CV) of SnO\(_2\) NSs (sample SA3), and the CV behavior is generally consistent with previous reports.\(^88\) Specifically in the first cycle, the two current peaks located at 0.8 and 0.03 V (cathodic) correspond to the formation of Li\(_2\)O and Li\(_2\)Sn, respectively. The anodic potential at 0.6 V indicates the reversible dealloying process. It should be noted that a broad cathodic peak (0.8–1.2 V) and a corresponding anodic peak (1.1–1.6 V) still exist during the fifth cycle, suggesting partial reversibility of reaction v. Note here, it has indeed been found that for the metallic Sn particles larger than 30 nm, the partial electrochemical reversibility of Li\(_2\)O is unable to activate.\(^{106–108}\) However, Poizot et al. studied the electrochemical properties of several transition metal oxides for the cathode materials and revealed the partial reversibility of Li\(_2\)O when applied nanosized particles (10–20 nm) with large surface areas.\(^109\) And this conclusion was further supported by Chang et al. in the SnO\(_2\) nanocrystalline cathode system.\(^110\) Besides, the partial reversibility of reaction v is also widely suggested in the recent literatures of SnO\(_2\) systems.\(^111–115\) On this basis, we believe that the observed partial reversibility of reaction v is due to the ultrathin thickness of SnO\(_2\) NSs. Figure 10b shows the charge−discharge voltage profile of SnO\(_2\) NSs sample measured at a constant current rate of 0.2 C (156 mA/g). In agreement with its CV behavior, two poorly defined plateau regions (0.9 and 0.25 V) can be identified in the first discharge process, and it gives a very high discharge capacity of 1742 mAh/g. The following charge process features a charge capacity of 762 mAh/g, contributing to a low Coulombic efficiency of 43.7%. This large initial capacity loss (~56%) is common for SnO\(_2\) materials, which is mainly owing to the first irreversible reactions. The discharge and charge capacities in the second cycle are 936 and 872 mAh/g, respectively, resulting in an increased efficiency value of 93.2%. Moreover, the efficiency further increases up to 97.0% in the fifth cycle and keeps increasing in the following cycles. The actual capacity of SnO\(_2\) NSs is clearly higher than its theoretical value (782 mAh/g) in the first few cycles. This phenomenon also suggests that the reaction v is partially reversible. Figure 10c displays the comparative performances among SnO\(_2\) NSs (SA3, BET surface area 180.3 m\(^2\)/g), hollow spheres (SA9, BET surface area 101.8 m\(^2\)/g), and NPs (SA10, BET surface area 199.7 m\(^2\)/g). It is evident that SnO\(_2\) NSs manifest a greatly enhanced lithium storage capability as compared to the two counterparts. After 50 discharge and charge cycles, a much higher reversible capacity of 534 mAh/g was delivered by SnO\(_2\) NSs, while the two counterparts only give 355 and 177 mAh/g, respectively. Moreover, the reversible capacity retention reached 68% for SnO\(_2\) NSs. This greatly enhanced storage capacity is mainly due to the ultrathin thicknesses and the unique porous structures: the nanometer-sized networks provide negligible diffusion.
times of ions and probably faster phase transitions, and the “breathable” interior spaces can effectively buffer drastic volume changes during the reactions. Nonetheless, in spite of this obvious advantage over its counterparts, we still believe that the performance of the SnO$_2$ NSs synthesized here can be improved. Lou et al. demonstrated that significant improvements in the cycle life of SnO$_2$-based anode could be readily achieved by carbon coating.$^{111,112,116-118}$ Thus, more studies are planned in the future.

### CONCLUSIONS

In summary, large-scale and highly pure ultrathin SnO$_2$ NSs have been successfully prepared by a simple chemical method, which were characterized by XRD, TEM, SEM, HRTEM, XPS, AFM, and UV–vis. It was found that SnO$_2$ NSs growth follows the “oriented attachment” mode. AFM height profile and HRTEM cross-section images showed a minimum thickness of ~2.1 nm, contributing to large quantum confinement in the thickness directions. The effects of reaction time, solvent, additive, precursor concentration, and cooling rate effect were systematically mapped. Inherent nonstoichiometry was straightforwardly observed in HRTEM images. Finally, lithium-ion storage behaviors of the SnO$_2$ NSs together with SnO$_2$ hollow spheres and NPs were studied. The results showed enhanced performance of SnO$_2$ NSs sample as compared to its two counterparts. This superior performance is directly brought by faster ion diffusions and better stability owing to the ultrathin thicknesses as well as the unique porous structures. The overall findings in this paper will shed new light on the fundamental properties of tin oxides, and on rational fabrication of new functional devices.

### ASSOCIATED CONTENT

1 Supporting Information

Additional XRD data; TEM and SEM images. This material is available free of charge via the Internet at http://pubs.acs.org.

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